Measurement Module for Strain Gage and LVDT/RVDT



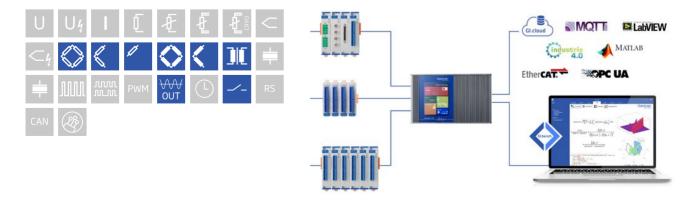
Q.raxx XE is an new addition to the Q.series product family - the ideal 19" rackmount EtherCAT DAQ solution for applications that require high channel density and custom sensor terminations. Q.raxx XE DAQ systems can consist of an integrated EtherCAT bus coupler for communication and 10 measurement modules capable of up to 100 kHz sampling per channel with short cycle times and low jitter for accurate synchronization

- According 19 "-standard IEC
- Electromagnetic Compatibility according to EN61000-4 and EN55011
- High density and flexibility with13 modules in one system in any constellation
- FoE (file access over EtherCAT, ETG.1000.5) and CoE (CAN over EtherCAT, ETG.50001.1)



Key Features

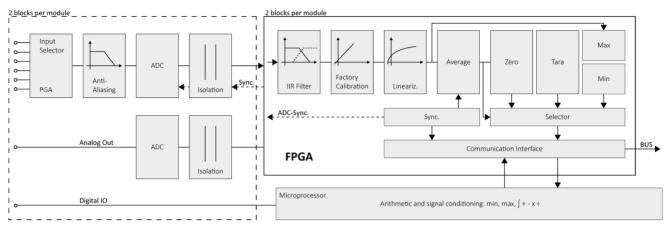
- 2 galvanically isolated analog inputs channels strain gage and inductive half and full bridges, LVDT, RVDT quarter bridge with completion terminal
- DC and carrier frequency (CF) principle
 2.5 and 5 VDC excitation, 2.5 and 5 VDCeff excitation carrier frequency,
 600 Hz or 4.8 kHz configurable per channel
- 2 Analog output channels
 ±10 VDC, 20 kHz update rate per channel
- High-accuracy digitization
 24-bit ADC, 20 kHz sample rate per channel
- 4 digital I/Os input: state, tare, memory reset, output: state, alarm, threshold
- Signal conditioning linearization, filtering, average, scaling, min/max, RMS, arithmetic, alarm
- 3-Way galvanic isolation
 500 VDC channel to channel, channel to power supply, and channel to bus





Measurement Module for Strain Gage and LVDT/RVDT

Block diagram



Technical Data

Analog Input

| Channels | 2 | |
|-------------------|--|--|
| Accuracy | 0.02 % typical | |
| | 0.05 % in controlled environment ¹ | |
| | 0.1 % in industrial area ² | |
| Linearity error | 0.02 % typical full-scale | |
| Repeatability | 0.01 % typical (within 24 hrs) | |
| Input impedance | >10 MΩ | |
| Isolation voltage | 500 VDC channel to channel, to power supply, channel to bus ³ | |
| | | |

 $^{\rm 1}\,$ according to EN 61326 2006: appendix B

² according to EN 61326 2006: appendix A

³ noise pulses up to 1000 VDC, continuous up to 250 VDC

Analog-to-Digital Conversion

| Resolution | 24-bit |
|----------------------|---|
| Sample rate | 20 kHz per channel |
| Modulation method | sigma-delta |
| Anti-aliasing filter | 2 kHz, 3th order (DC excitation) 1 kHz, 3th order (4.8 kHz CF excitation) 100 Hz, 3th order (600 Hz CF excitation) |
| Digital filters | Infinite impulse response (IIR), low-pass, high-pass, band-pass, band-stop, Butterworth or Bessel (2nd, 4th, 6th or 8th order), frequency range 0.1 Hz to 1 kHz in steps of 0.1 (adjustable via software) |
| Averaging | configurable or automatic according to the user-defined data rate |



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Analog Output

| Channels | 2 | | |
|---------------------------|--------------------------|----------------------------|--|
| | | | |
| Accuracy | 0.02 % typical | 0.02 % typical | |
| Voltage output | ±10 VDC | | |
| Allowable load resistance | >2 kΩ | | |
| Long-term drift | <1 mV / 24 hrs | <2.5 mV / 8000 hrs | |
| Temperature drift | <1 mV /10 K Offset drift | < 0.05 % / 10 K Gain drift | |
| Noise voltage | <2 mV at 10 Hz | <10 mV at 1 kHz | |

Digital Input & Output

| 4 configurable I/Os |
|---|
| status |
| <2 VDC (Low) >10 VDC (High) |
| PNP (current sinking) |
| 30 VDC max. |
| 10 to 30 VDC (external supply required) |
| open drain p-channel MOSFET |
| 30 VDC / 100 mA (ohmic load) |
| |

Strain Gage Measurement

| Bridge configuration(s) | resistive full-bridge (4/6-wire) resistive half-bridge (3/5-wire) resistive quarter-bridge 120 Ω or 350 Ω (3-wire, with bridge completion terminal) | | | |
|------------------------------------|---|-------------|--|---------------|
| Allowable sensor cable length | < 300 m (DC and 600 Hz CF excitation) <100 m ¹ (4.8 kHz CF excitation) | | | |
| Shunt resistor | 100 kΩ internal resistor | | | |
| Bridge excitation | 2.5 - 5 VDC 2.5 - 5 Veff (Carrier Frequency) | | | |
| Bridge excitation stability | <0.01% / 24 hrs | | | |
| Bridge excitation drift | <0.02% / 10 K | | | |
| | 5 VDC | 5 Veff (CF) | 2.5 VDC | 2.5 Veff (CF) |
| Allowable sensor resistance | >300 Ω | > 300 Ω | >100 Q | >100 Q |
| Input range | ±1.25 mV/V | ±1.25 mV/V | ±2.5 mV/V | ±2.5 mV/V |
| | ±2.5 mV/V | ±2.5 mV/V | ±5 mV/V | ±5 mV/V |
| | ±25 mV/V | ±25 mV/V | ±50 mV/V | ±50 mV/V |
| | ±50 mV/V | ±50 mV/V | ±100 mV/V | ±100 mV/V |
| | ±100 mV/V | ±100 mV/V | ±200 mV/V | ±200 mV/V |
| | ±200 mV/V | ±200 mV/V | ±400 mV/V | ±400 mV/V |
| | ±500 mV/V | ±500 mV/V | ±1000 mV/V | ±1000 mV/V |
| Long-term stability | <0.2 µV/V / 24 hrs (DC excitation) <0.1 µV/V / 24 hrs (CF excitation) | | <pre><2 µV/V / 8000 hrs (DC <1 µV/V / 8000 hrs (CF</pre> | , |
| Temperature drift (range 2.5 mV/V) | <0.2 µV/V / 10 K Offset drift | | < 0.05 % / 10 K Gain dri | ft |
| Signal-to-noise ratio | < 0.3 µV/V at 10 Hz | | <1 µV/V at 100 Hz | |

 $^{\rm 1}\,$ low capacity sensor cable is strongly recommended

Measurement Module for Strain Gage and LVDT/RVDT



LVDT/RVDT Measurement

| Sensor connection | 4-/6-wire | |
|------------------------------------|-------------------------------|----------------------------|
| Sensor excitation (selectable) | 5 Veff | 2.5 Veff |
| Allowable sensor resistance | >300 Ω | >100 Q |
| Input range | ±1.25 mV/V | ±2.5 mV/V |
| | ±2.5 mV/V | ±5 mV/V |
| | ±25 mV/V | ±50 mV/V |
| | ±50 mV/V | ±100 mV/V |
| | ±100 mV/V | ±200 mV/V |
| | ±200 mV/V | ±400 mV/V |
| | ±500 mV/V | ±1000 mV/V |
| Allowable sensor cable length | <100 m ¹ | |
| Long-term stability | <0.1 µV/V / 24 hrs | <1 µV/V / 8000 hrs |
| Temperature drift (range 2.5 mV/V) | <0.2 µV/V / 10 K Offset drift | < 0.05 % / 10 K Gain drift |
| Signal-to-noise ratio | < 0.3 µV/V at 10 Hz | <1 µV/V at 100 Hz |
| | | |

¹ low capacity sensor cable is strongly recommended

Digital-to-Analog Conversion

| Resolution | 16-bit |
|---------------|--------------------|
| Update rate | 20 kHz per channel |
| Settling time | βμs |

Communication Interface EtherCAT

| Electrical standard | RS-485, 2-wire |
|---------------------|-----------------|
| Protocols | EtherCAT (LVDS) |

Power Supply

| Input voltage | 10 to 30 VDC, overvoltage and overcurrent protection |
|-------------------------|--|
| Power consumption | 2.5 W (approx.) |
| Input voltage influence | <0.001 % / V |

Environmental Specifications

| Electromagnetic compatibility (EMC) | according to IEC 61000-4 and EN 55011 |
|-------------------------------------|---------------------------------------|
| Operating temperature | -20°C to +60°C |
| Storage temperature | -40°C to +85°C |
| Relative humidity | 5 - 95 % at 50°C (non-condensing) |

Remarks

Validity of all listed specifications are subject to a warm-up period of at least 45 minutes
Specifications subject to change without notice

Measurement Module for Strain Gage and LVDT/RVDT



Mechanical information

| Material | Aluminum |
|--------------------------|-----------------|
| Measurements (W x H x D) | 30x 128 x 120mm |
| Weight | approx. 200 g |

Ordering Information

| Article number | 517425 |
|----------------|---|
| | Terminal B4/120-A106, article number 894387 |
| Accessories | Terminal B4/350-A106, article number 894488 |

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